Session Title	**[MoC3] Topological Materials**
Date / Time	July 2 (Mon.), 2018 / 15:55-17:30
Room	Room C (#107)
Session Chair	TBA

MoC3-I1 (Invited) **15:55-16:20**

Revealing Topological Edge States in Bismuth Nanowires by Proximity Induced Superconductivity

Helene Bouchiat[1], Anil Murani[2], Kasumov Alik[1], and Gueron Sophie[1]
[1]CNRS France, France, [2]CEA Saclay, France

MoC3-I2 (Invited) **16:20-16:45**

Large Anomalous Hall Current Induced by Topological Nodal Lines in A Ferromagnetic Van Der Waals Material

Kyoo Kim[1], Junho Seo[2], Eunwoo Lee[3], Jong Mok Ok[2], Jinwon Lee[2], Youn Jung Jo[4], Woun Kang[5], Han Woong Yeom[2], Ji Hoon Shim[6], Byung Il Min[6], Bohm-Jung Yang[3], and Jun Sung Kim[2]
[1]MPK POSTECH, Korea, [2]POSTECH & IBS-CALDES, Korea, [3]Seoul Nat'l Univ., Korea, [4]Kyungpook Nat'l Univ., Korea, [5]Ewha Womans Univ., Korea, [6]POSTECH, Korea

MoC3-I3 (Invited) **16:45-17:10**

Characteristic Frequency Dependence of Optical Conductivity in Topological Semimetals

Hongki Min
Seoul Nat'l Univ., Korea

MoC3-I4 (Invited) **17:10-17:35**

Topological Phases in Thin Films of Materials with Inverted Band Structures

Fedor Kusmartsev[1], Yi Luo[2], Aidan Wilkonson[2], He Li[2], Anna Kusmartsev[1], and Marat Gaifullin[1]
[1]Loughborough Univ., UK, [2]MTRC, China